MM54HC51/MM74HC51 Dual AND-OR-Invert Gate MM54HC58/MM74HC58 Dual AND-OR Gate

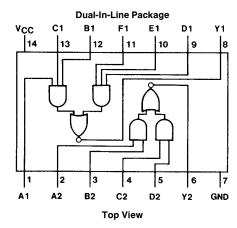
General Description

These gates utilize advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits. All gates have buffered outputs, providing high noise immunity and the ability to drive 10 LS-TTL loads. The 54HC/74HC logic family is functionally as well as pin-out compatible with the standard 54LS/74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to $V_{\mbox{\footnotesize CC}}$ and ground.

Features

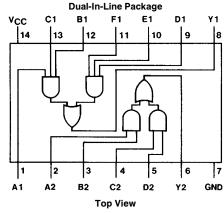
- Typical propagation delay: 10 ns
- Wide power supply range: 2-6V
- Low quiescent supply current: 20 µA maximum (74 Series)
- Low input current: 1 µA maximum
- High output current: 4 mA minimum

Connection Diagrams



TL/F/5302-1

Order Number MM54HC51 or MM74HC51



TL/F/5302-2

Order Number MM54HC58 or MM74HC58

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V _{CC})	-0.5 to $+7.0$ V
DC Input Voltage (V _{IN})	-1.5 to $V_{\rm CC}$ + 1.5 V
DC Output Voltage (V _{OUT})	-0.5 to $V_{\rm CC}$ $+$ 0.5 $V_{\rm CC}$
Clamp Diode Current (I _{IK} , I _{OK})	\pm 20 mA
DC Output Current, per pin (IOUT)	\pm 25 mA
DC V _{CC} or GND Current, per pin (I _{CC})	\pm 50 mA
Storage Temperature Range (T _{STG})	-65°C to +150°C
D D: : :: (D)	

 Power Dissipation (PD)
 600 mW

 (Note 3)
 600 mW

 S.O. Package only
 500 mW

 Lead Temp. (TL) (Soldering 10 seconds)
 260°C

Operating Conditions							
	Min	Max	Units				
Supply Voltage (V _{CC})	2	6	V				
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V				
Operating Temp. Range (T _A)							
MM74HC	-40	+85	°C				
MM54HC	-55	+125	°C				
Input Rise or Fall Times							
$(t_r, t_f) V_{CC} = 2.0V$		1000	ns				
$V_{CC} = 4.5V$		500	ns				
$V_{CC} = 6.0V$		400	ns				

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	v _{cc}	T _A = 25°C		74HC T _A = -40 to 85°C	54HC T _A = -55 to 125°C	Units	
				Typ Guaranteed Limits					
V _{IH}	Minimum High Level		2.0V		1.5	1.5	1.5	٧	
	Input Voltage		4.5V		3.15	3.15	3.15	V	
			6.0V		4.2	4.2	4.2	V	
V _{IL}	Maximum Low Level		2.0V		0.5	0.5	0.5	٧	
	Input Voltage**		4.5V		1.35	1.35	1.35	V	
	·		6.0V		1.8	1.8	1.8	V	
V _{OH}	Minimum High Level	V _{IN} =V _{IH} or V _{IL}							
	Output Voltage	I _{OUT} ≤20 μA	2.0V	2.0	1.9	1.9	1.9	V	
			4.5V	4.5	4.4	4.4	4.4	V	
			6.0V	6.0	5.9	5.9	5.9	٧	
		V _{IN} =V _{IH} or V _{IL}							
		I _{OUT} ≤4.0 mA	4.5V	4.2	3.98	3.84	3.7	V	
		I _{OUT} ≤5.2 mA	6.0V	5.7	5.48	5.34	5.2	V	
V _{OL}	Maximum Low Level	V _{IN} =V _{IH} or V _{IL}							
	Output Voltage	I _{OUT} ≤20 μA	2.0V	0	0.1	0.1	0.1	V	
			4.5V	0	0.1	0.1	0.1	V	
			6.0V	0	0.1	0.1	0.1	٧	
		V _{IN} =V _{IH} or V _{IL}							
		I _{OUT} ≤4.0 mA	4.5V	0.2	0.26	0.33	0.4	V	
		I _{OUT} ≤5.2 mA	6.0V	0.2	0.26	0.33	0.4	٧	
I _{IN}	Maximum Input Current	V _{IN} =V _{CC} or GND	6.0V		±0.1	±1.0	±1.0	μΑ	
ICC	Maximum Quiescent Supply Current	V _{IN} =V _{CC} or GND I _{OUT} =0 μA	6.0V		2.0	20	40	μΑ	

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

 $\textbf{Note 3:} \ Power \ Dissipation \ temperature \ derating -- plastic \ "N" \ package: -12 \ mW/°C \ from \ 65°C; \ ceramic \ "J" \ package: -12 \ mW/°C \ from \ 100°C \ to \ 125°C.$

Note 4: For a power supply of 5V \pm 10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

^{**} V_{IL} limits are currently tested at 20% of V_{CC} . The above V_{IL} specification (30% of V_{CC}) will be implemented no later than Q1, CY'89.

AC Electrical Characteristics $v_{CC}\!=\!5\text{V},\,T_{A}\!=\!25^{\circ}\text{C},\,C_{L}\!=\!15\,\text{pF},\,t_{r}\!=\!t_{f}\!=\!6\,\text{ns}$

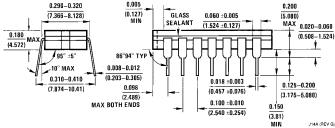
Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t _{PHL} , t _{PLH}	Maximum Propagation Delay		10	20	ns

$\textbf{AC Electrical Characteristics} \ \ V_{CC} = 2.0 \ V \ \text{to 6.0V, C}_L = 50 \ \text{pF, t}_r = t_f = 6 \ \text{ns (unless otherwise specified)}$

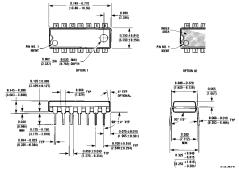
Symbol	Parameter	Conditions	v _{cc}	V _{CC} T _A =25°C		T _A =25°C		T _A =25°C		74HC T _A = -40 to 85°C	54HC T _A = -55 to 125°C	Units
				Тур	p Guaranteed Limits							
t _{PHL} , t _{PLH}	Maximum Propagation Delay		2.0V 4.5V 6.0V	63 13 11	125 25 21	158 32 27	186 37 32	ns ns ns				
t _{TLH} , t _{THL}	Maximum Output Rise and Fall Time		2.0V 4.5V 6.0V	30 8 7	75 15 13	95 19 16	110 22 19	ns ns ns				
C _{PD}	Power Dissipation Capacitance (Note 5)	(per AND-OR-Gate)		20				pF				
C _{IN}	Maximum Input Capacitance			5	10	10	10	pF				

 $\textbf{Note 5:} C_{PD} \ \text{determines the no load dynamic power consumption, } P_D = C_{PD} \ V_{CC}^2 \ f + I_{CC} \ V_{CC}, \ \text{and the no load dynamic current consumption, } I_S = C_{PD} \ V_{CC} \ f + I_{CC}.$

Physical Dimensions inches (millimeters) 0.785 (19.939) MAX [14] [13] [12] [11] [10] [9] [8] 0.025 (0.635) RAD 0.220-0.310 (5.588-7.874) 1 2 3 4 5 6 7



Order Numbers MM54HC51J, MM54HC58J, MM74HC51J, MM74HC58J NS Package J14A



Order Numbers MM74HC51N, MM74HC58N NS Package N14A

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